Supplementary Material

Two-dimensional Janus Semiconductors BiTeCl and BiTeBr monolayers: A first-principles study of the tunable electronic properties via electric field and mechanical strain

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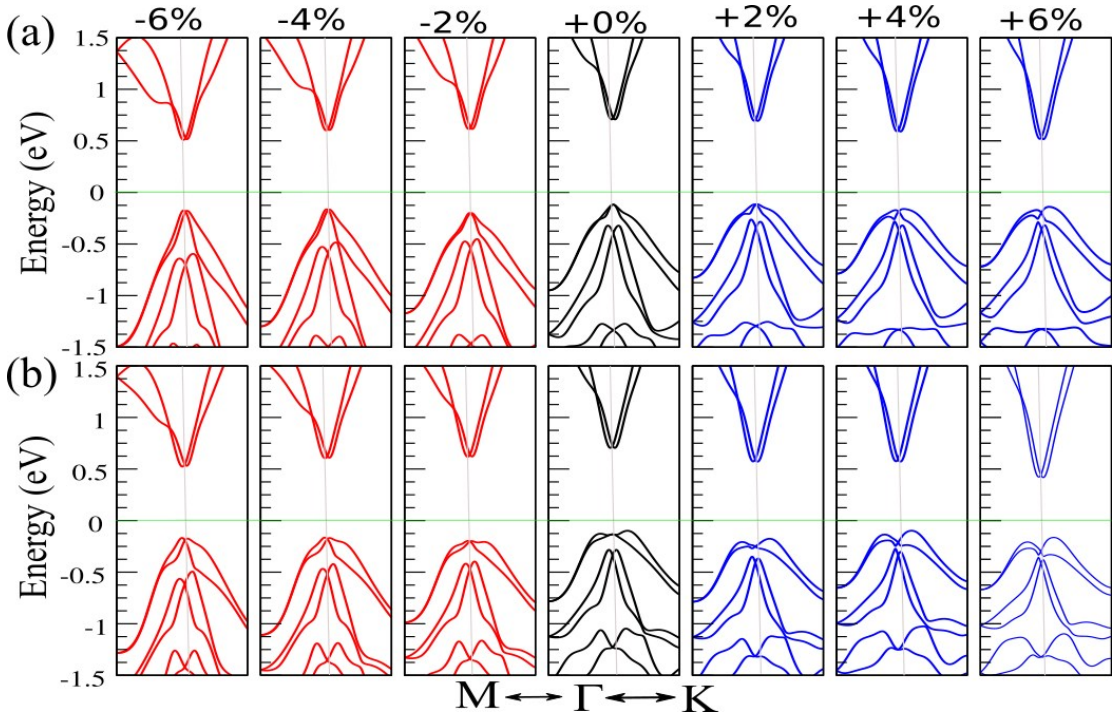

Figure S1: The electronic band structure of the BiTeCl monolayer under the influence of uniaxial strain.

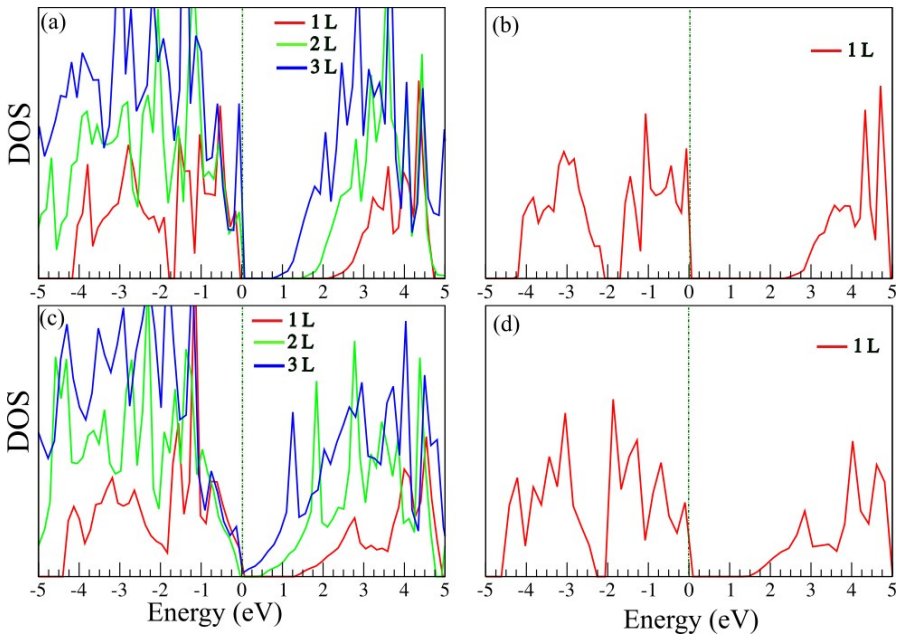

Figure S2: Electronic density of states using HSE of the (a) BiTeBr and (b) BiTeCl .Electronic density of states using HSE+SOC of (c) BiTeBr (d) BiTeCl monolayers.